



# UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE  
United States Patent and Trademark Office  
Address: COMMISSIONER FOR PATENTS  
P.O. Box 1450  
Alexandria, Virginia 22313-1450  
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/760,084	01/16/2004	Mikiko Abe	71801 CCD	1283

7590 05/03/2007  
c/o Cooper & Dunham LLP  
1185 Ave. of the Americas  
New York, NY 10036

EXAMINER
----------

ANGEBRANNDT, MARTIN J

ART UNIT	PAPER NUMBER
----------	--------------

1756

MAIL DATE	DELIVERY MODE
-----------	---------------

05/03/2007

PAPER

**Please find below and/or attached an Office communication concerning this application or proceeding.**

The time period for reply, if any, is set in the attached communication.

<b>Office Action Summary</b>	<b>Application No.</b> 10/760,084	<b>Applicant(s)</b> ABE ET AL.	
	<b>Examiner</b> Martin J. Angebrändt	<b>Art Unit</b> 1756	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

#### Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

#### Status

- 1) ☒ Responsive to communication(s) filed on 2/5/07.
- 2a) ☐ This action is **FINAL**.                      2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

#### Disposition of Claims

- 4) ☒ Claim(s) 1,2,4-6 and 9-12 is/are pending in the application.
- 4a) Of the above claim(s) \_\_\_\_\_ is/are withdrawn from consideration.
- 5) ☐ Claim(s) \_\_\_\_\_ is/are allowed.
- 6) ☒ Claim(s) 1,2,4-6 and 9-12 is/are rejected.
- 7) ☐ Claim(s) \_\_\_\_\_ is/are objected to.
- 8) ☐ Claim(s) \_\_\_\_\_ are subject to restriction and/or election requirement.

#### Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on \_\_\_\_\_ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.  
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).  
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

#### Priority under 35 U.S.C. § 119

- 12) ☐ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All    b) ☐ Some \*    c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
  2. ☐ Certified copies of the priority documents have been received in Application No. \_\_\_\_\_.
  3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

\* See the attached detailed Office action for a list of the certified copies not received.

#### Attachment(s)

- |  |   |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892)                                | 4) <input type="checkbox"/> Interview Summary (PTO-413)<br>Paper No(s)/Mail Date. _____ |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948)                       | 5) <input type="checkbox"/> Notice of Informal Patent Application                       |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08)<br>Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____  |

Art Unit: 1756

1. The response of the applicant has been read and given careful consideration. Rejections of the previous office action are withdrawn based upon the amendments and arguments of the applicant. Responses to the arguments of the applicant appear after the first rejection to which it is directed. The applicant has perfected priority through the certified translations provided.

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

3. Claims 1,2,4-6, and 9-11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Onaki et al. JP 2002-260283, in view of Ebina et al. JP 10-055539 and Nobukuni et al. '407 or Harigaya et al. EP 1260973.

Onaki et al. JP 2002-260283 (machine translation attached) teaches in example 2, a substrate with a 65 nm ZnS-  $\text{Nb}_2\text{O}_5$  lower protective layer, a 5 nm second lower dielectric layer of  $(\text{ZrO}_2)_{80}(\text{Nb}_2\text{O}_5)_{20}$ , a 15 nm  $\text{In}_5\text{Sb}_{62}\text{Te}_{30}\text{Ge}_3$  recording layer, a 16 nm dielectric layer of  $(\text{ZrO}_2)_{80}(\text{Nb}_2\text{O}_5)_{20}$ , a AgCu reflective layer of 150 nm. Examples 4 uses  $\text{ZrO}_2$ -MgO [0087], example 5 uses  $\text{ZrO}_2$ -CaO [0090]. The use of a bilayer lower dielectric protective layer, where the layer closest to the recording layer acts as a barrier layer and zirconia materials are preferred [0041,0047-0048]. Another example uses  $\text{ZrO}_2$ - $\text{Y}_2\text{O}_3$ - $\text{TiO}_2$  [0093]. The use of zirconia stabilized using various materials is disclosed. [0019,0068].

Ebina et al. JP 10-055539 in example 1 teaches a grooved substrate coated with a 150 nm ZnS- $\text{SiO}_2$  lower protective layer, a 25 nm  $\text{Sb}_2\text{Te}_5\text{Ge}_2$  recording layer, a 50 nm ZnS- $\text{SiO}_2$  upper protective layer, a 100 nm Al reflective layer [0016]. This was initialized with a power density

Art Unit: 1756

of  $17.5 \text{ mW}/\mu\text{m}^2$  at a linear velocity of 8.0 m/s with an advance of 48 microns. [0017]. The laser beams used was a  $100 \times 1$  micron oval laser beam (area being  $78.5 \mu\text{m}^2$  [0017]. The use of the medium at velocities of 8.4 m/s is disclosed. [0017]. The use of velocities of 3-12 m/s is disclosed/ [0009]. The use of power densities of  $7.5\text{-}20 \text{ mW}/\mu\text{m}^2$  is disclosed [0010]. The use of various phase change recording layers including InSbTe and GeTeSb recording layers is disclosed [0014]. The power of the laser is varied inversely with speed.

Nobukuni et al. '407 teaches example 1, which has a InGeSbTe recording layer and is initialized at 3-4 m/s and a power of 600-700 mW over an area of  $71.4 \mu\text{m}^2$ . The power is  $\sim 9.8 \text{ mW}/\mu\text{m}^2$ . [0549]. The use of the medium at 10 times velocity is taught ( $\sim 12.0 \text{ m/s}$ ). [0556-0572]. The general use of GeTeSb and InGeSbTe recording layers is disclosed [0160,0166,0179].

Harigaya et al. EP 1260973 in example 1 teaches a substrate with a 0.74 micron pitch groove coated with a 68 nm ZnS-SiO<sub>2</sub> lower protective layer, a 16 nm GeMnSbTe recording layer, a 10 nm 77% ZrO<sub>2</sub>-3% Y<sub>2</sub>O<sub>3</sub>-20% TiO<sub>2</sub> upper interfacial layer and a 140 nm Ag reflective layer. [0142-0149]. This was initialized with a laser power of 850 mW at a linear velocity of 3 m/s and a feed of 36 microns/r [0152]. The laser beams used was a  $196 \times 1$  micron oval laser beam and each area was irradiated and average of 5.4 times (area being  $153 \mu\text{m}^2$ ) [0152]. The use of the medium at 17.5 m/s is disclosed [0152].

It would have been obvious to one skilled in the art to modify example 2 of Onaki et al. JP 2002-260283 by using CaO, MgO and or ReO based upon the direction at [0019,0068,0078,0090] and using the initialization process of Ebina et al. JP 10-055539 with a reasonable expectation of being able to initialize the media at velocities of 8-12 m/s at power

Art Unit: 1756

densities of 15-20 mW/  $\mu\text{m}^2$  based upon the similarity with the media of Nobukuni et al. '407 or Harigaya et al. EP 1260973 which are disclosed as functioning at higher velocities as well.

Further it would have been obvious to modify the process by using CaO, MgO and or ReO in combination with  $\text{ZrO}_2$  and up to 20%  $\text{TiO}_2$  based upon the direction at [0019]. Note that Ebina et al. JP 10-055539 teaches the recording media can be used at velocities of 3-12 m/s with embraces the value taught for Onaki et al. JP 2002-260283.

The addition of Onaki et al. JP 2002-260283 addresses the arguments by the applicant based upon  $\text{ZrO}_2$  dielectric layers.

4. Claims 1,2,4-6, and 9-12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Onaki et al. JP 2002-260283, in view of Ebina et al. JP 10-055539 (machine translation enclosed), Nobukuni et al. '407 or Harigaya et al. EP 1260973, further in view of Maeda et al. '375.

Maeda et al. '375 disclose the initialization of phase change recording media in only the groove or land areas.

In addition to the basis above, to address the embodiments bounded by the claims where multiple irradiation does not occur, the examiner holds that it would have been obvious to one skilled in the art to modify the processes rendered obvious by the combination of Onaki et al. JP 2002-260283, Ebina et al. JP 10-055539, Nobukuni et al. '407 or Harigaya et al. EP 1260973 by initializing only the land or groove regions as taught by Maeda et al. '375 to reduce the time required for initialization.

5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Art Unit: 1756

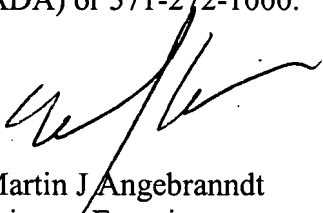
Yamashita et al. EP 475452, Yura JP 01-258222 and JP 61-180945 teach optical recording media with stabilized zirconia dielectric layers.

6. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Martin J. Angebrannndt whose telephone number is 571-272-1378.

The examiner can normally be reached on Monday-Thursday and alternate Fridays.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Mark Huff can be reached on 571-272-1385. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.



Martin J. Angebrannndt  
Primary Examiner  
Art Unit 1756

04/26/2007